

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	66.4204	N/A	9.0640
RT2	11.1431	N/A	2.7529
RT3	64.0084	N/A	7.5910
RT4	24.8037	N/A	30.5802
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.3683	N/A	4.1353m
CT2	324.4026m	N/A	279.2346u
CT3	6.0954m	N/A	235.0834m
CT4	1.0586m	N/A	12.4041m

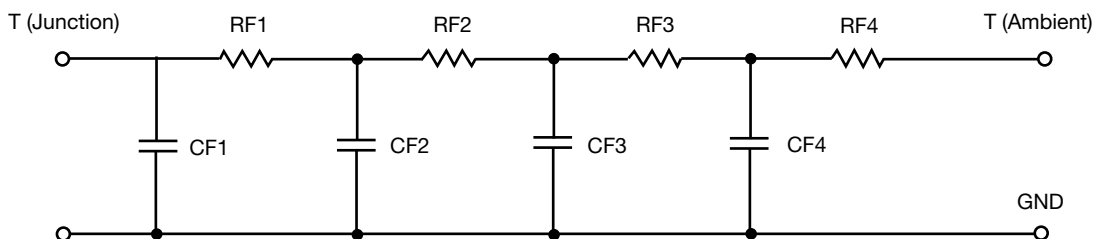
Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	12.7852	N/A	4.5767
RF2	51.7144	N/A	19.6106
RF3	35.9552	N/A	23.0119
RF4	65.6044	N/A	3.2552
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	423.3505u	N/A	418.7427u
CF2	2.1262m	N/A	3.7693m
CF3	20.7106m	N/A	15.4893m
CF4	1.3310	N/A	1.0588

Note

N/A indicates not applicable

